PNP -100mA -50V Digital Transistors (Bias Resistor Built-in Transistors)

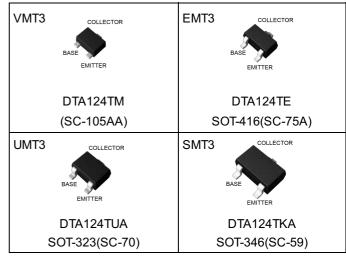
Datasheet

Parameter	Value
V _{CEO}	-50V
I _C	-100mA
R ₁	22kΩ

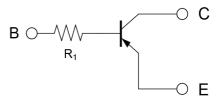
Features

- 1) Built-In Biasing Resistor
- 2) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see inner circuit).
- 3) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of completely eliminating parasitic effects.
- 4) Only the on/off conditions need to be set for operation, making the circuit design easy.
- 5) Complementary NPN Types: DTC124T series
- 6) Lead Free/RoHS Compliant.

Outline



•Inner circuit



Application

Switching circuit, Inverter circuit, Interface circuit,

Driver circuit

B: BASE

C: COLLECTOR

E: EMITTER

Packaging specifications

or dokaging opcomeducing							
Part No.	Package	Package size	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit.(pcs)	Marking
DTA124TM	VMT3	1212	T2L	180	8	8000	95
DTA124TE	EMT3	1616	TL	180	8	3000	95
DTA124TUA	UMT3	2021	T106	180	8	3000	95
DTA124TKA	SMT3	2928	T146	180	8	3000	95

● Absolute maximum ratings (T_a = 25°C)

Parameter			Values	Unit
Collector-base voltage		V_{CBO}	-50	V
Collector-emitter voltage		V _{CEO}	-50	V
Emitter-base voltage			-5	V
Collector current		I _C	-100	mA
	DTA124TM		150	mW
Dayyar dissination	DTA124TE	D *1	150	
Power dissipation	DTA124TUA	P _D *1	200	
	DTA124TKA		200	
Junction temperature		T _j	150	°C
Range of storage temperature		T _{stg}	-55 to +150	°C

● Electrical characteristics (T_a = 25°C)

Doromotor	Cumbal	Conditions		Values		Lloit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-base breakdown voltage	BV _{CBO}	I _C = -50μA	-50	-	-	V
Collector-emitter breakdown voltage	BV _{CEO}	I _C = -1mA	-50	-	-	V
Emitter-base breakdown voltage	BV _{EBO}	I _E = -50μA	-5	-	-	V
Collector cut-off current	I _{CBO}	V _{CB} = -50V	-	-	-0.5	μA
Emitter cut-off current	I _{EBO}	V _{EB} = -4V	-	-	-0.5	μA
Collector-emitter saturation voltage	V _{CE(sat)}	$I_{C} / I_{B} = -5 \text{mA} / -0.5 \text{mA}$	-	-	-0.3	V
DC current gain	h _{FE}	$V_{CE} = -5V, I_{C} = -1mA$	100	250	600	-
Input resistance	R ₁	-	15.4	22	28.6	kΩ
Transition frequency	f _T *2	V _{CE} = -10V, I _E = 5mA, f = 100MHz	-	250	-	MHz

^{*1} Each terminal mounted on a reference footprint

^{*2} Characteristics of built-in transistor

● Electrical characteristic curves(Ta=25°C)

Fig.1 Grounded emitter propagation characteristics

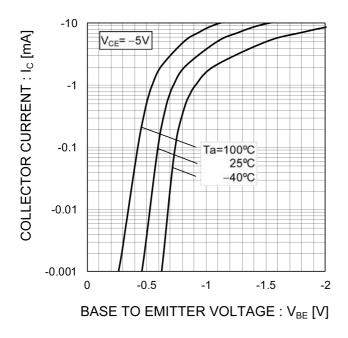


Fig.2 Grounded emitter output characteristics

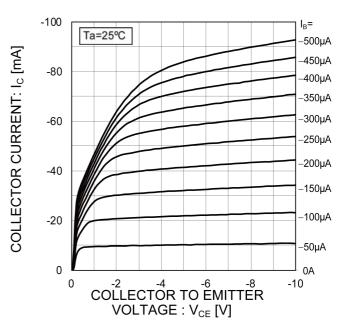


Fig.3 DC Current gain vs. Collector Current

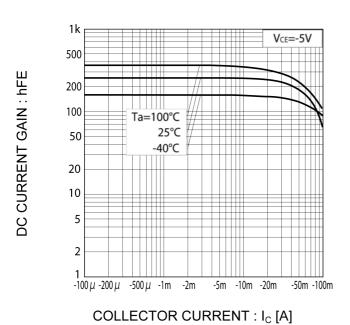
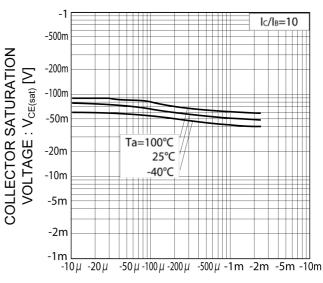


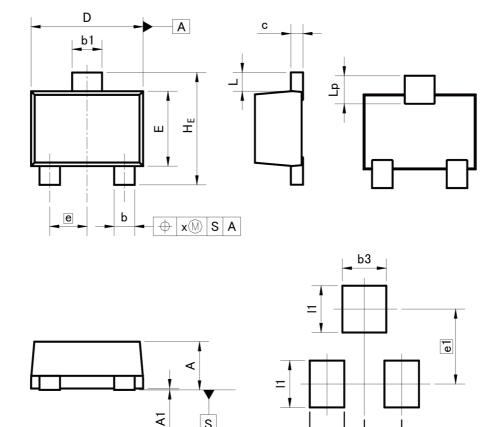
Fig.4 Collector-emitter saturation voltage vs.

Collector Current



COLLECTOR CURRENT: Ic [A]





S

Pattern of terminal position areas [Not a recommended pattern of soldering pads]

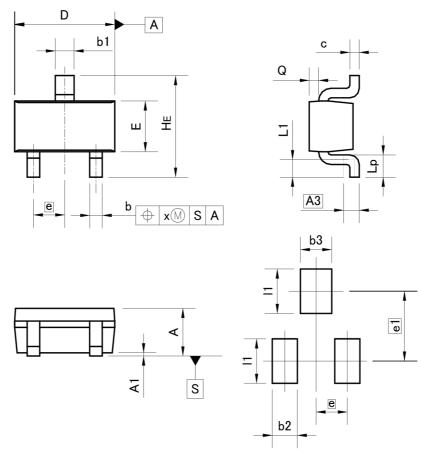
b2

DIM -	MILIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	0.45	0.55	0.018	0.022
A1	0.00	0.10	0.000	0.004
b	0.17	0.27	0.007	0.011
b1	0.27	0.37	0.011	0.015
С	0.08	0.18	0.003	0.007
D	1.10	1.30	0.043	0.051
E	0.70	0.90	0.028	0.035
е	0.40		0.02	
HE	1.10	1.30	0.043	0.051
L	0.10	0.30	0.004	0.012
Lp	0.20	0.40	0.008	0.016
х	2	0.10		0.004
DIM	MILIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
b2	=	0.37	-	0.015
b3	: :	0.47	-	0.019
e1	0.	80	0.0	31
11	-	0.50	-	0.020

Dimension in mm/inches



EMT3



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

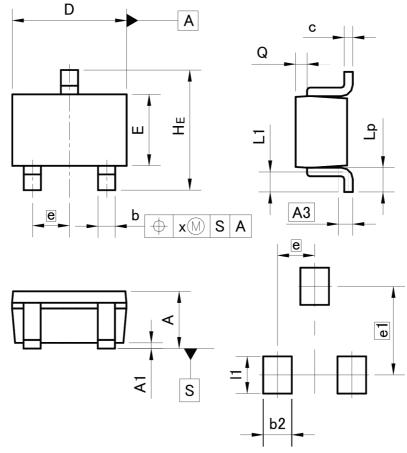
DIM	MILIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	0.60	0.80	0.024	0.031
A1	0.00	0.10	0.000	0.004
A3	0.	25	0.0	10
b	0.15	0.30	0.006	0.012
b1	0.25	0.40	0.010	0.016
С	0.10	0.20	0.004	0.008
D	1.50	1.70	0.059	0.067
E	0.70	0.90	0.028	0.035
е	0.	50	0.0	20
HE	1.40	1.80	0.055	0.071
L1	0.10	 8	0.004	.m.:
Lp	0.15	50	0.006	TT.
Q	0.05	0.25	0.002	0.010
х	100	0.10	_	0.004

DIM	MILIM	ETERS	INC	HES
	MIN	MAX	MIN	MAX
b2	77.L	0.40	. 	0.016
b3		0.50	7	0.020
e1	1.	10	0.0	043
11	= 5	0.70		0.028

Dimension in mm/inches



UMT3



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

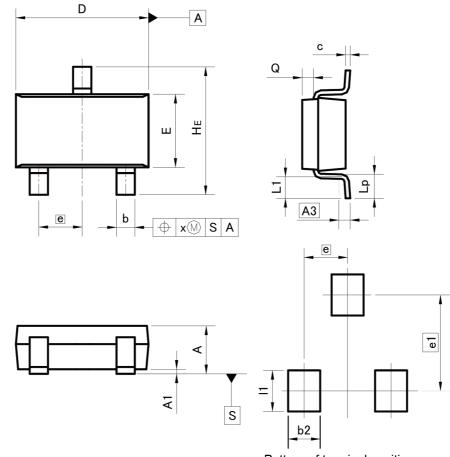
DIM	MILIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	0.80	1.00	0.031	0.039
A1	0.00	0.10	0.000	0.004
A3	0.2	25	0.0	10
b	0.15	0.30	0.006	0.012
С	0.10	0.20	0.004	0.008
D	1.90	2.10	0.075	0.083
E	1.15	1.35	0.045	0.053
е	0.0	65	0.0	26
HE	2.00	2.20	0.079	0.087
L1	0.20	0.50	0.008	0.020
Lp	0.25	0.55	0.010	0.022
Q	0.10	0.30	0.004	0.012
x	=	0.10	=======================================	0.004

DIM MILI	MILIM	MILIMETERS		HES
DIM	MIN	MAX	MIN	MAX
b2		0.50	_	0.020
e1	1.	55	0.0	061
11	_	0.65	_	0.026

Dimension in mm/inches



SMT3



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

MILIM	ETERS	INC	HES
MIN	MAX	MIN	MAX
1.00	1.30	0.039	0.051
0.00	0.10	0.000	0.004
0.:	25	0.0	10
0.35	0.50	0.014	0.020
0.09	0.25	0.004	0.010
2.80	3.00	0.110	0.118
1.50	1.80	0.059	0.071
0.95		0.037	
2.60	3.00	0.102	0.118
0.30	0.60	0.012	0.024
0.40	0.70	0.016	0.028
0.20	0.30	0.008	0.012
2	0.10		0.004
<u>(27)</u>	0.10	-	0.004
MILIM	FTERS	INC	HES
			MAX
	0.60	_	0.024
		0.0	83
	MIN 1.00 0.00 0.35 0.09 2.80 1.50 0.260 0.30 0.40 0.20 MILIM MIN -	1.00 1.30 0.00 0.10 0.25 0.35 0.50 0.09 0.25 2.80 3.00 1.50 1.80 0.95 2.60 3.00 0.30 0.60 0.40 0.70 0.20 0.30 - 0.10 - 0.10 MILIMETERS MIN MAX	MIN MAX MIN 1.00 1.30 0.039 0.00 0.10 0.000 0.25 0.0 0.35 0.50 0.014 0.09 0.25 0.004 2.80 3.00 0.110 1.50 1.80 0.059 0.95 0.05 2.60 3.00 0.102 0.30 0.60 0.012 0.40 0.70 0.016 0.20 0.30 0.008 - 0.10 - - 0.10 - MILIMETERS INC MIN MAX MIN - 0.60 -

Dimension in mm/inches

e1



0.035

0.90

Notes

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